

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE01H16 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

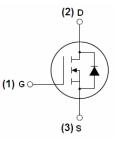
- $V_{DS} = 100V, I_D = 160A$ $R_{DS(ON)} < 5.0 m\Omega @ V_{GS} = 10V$ (Typ:3.8 m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Load switching
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01H16	NCE01H16	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	100	V	
Gate-Source Voltage	V _G s	±20	V	
Drain Current-Continuous	I _D	160	А	
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	113	А	
Pulsed Drain Current	I _{DM}	550	Α	
Maximum Power Dissipation	P _D	370	W	
Derating factor		2.5	W/℃	
Single pulse avalanche energy (Note 5)	Eas	1400	mJ	



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NCE01H16

Parameter	Symbol	Limit	Unit
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$
Thermal Characteristic			
Thermal Resistance, Junction-to-Case ^(Note 2)	Raic	0.4	°C/W

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter Symbol		Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	100	110	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3.2	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	3.8	5.0	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	70	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C _{lss}	\/ -50\/\/ -0\/	-	8500	-	PF
Output Capacitance	C _{oss}	V_{DS} =50V, V_{GS} =0V,	-	770	-	PF
Reverse Transfer Capacitance	$C_{\sf rss}$	F=1.0MHz	-	300	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	28	-	nS
Turn-on Rise Time	t _r	V_{DD} =50V, R_L =2.5 Ω	-	22	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =3 Ω	-	43.5	-	nS
Turn-Off Fall Time	t _f		-	14.5	-	nS
Total Gate Charge	Qg	V -50VI -20A	-	139	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=50V,I_{D}=20A,$	-	34	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	56	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =20A	-	0.85	1.2	V
Diode Forward Current (Note 2)	Is		-	-	160	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =20A	-	60	90	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	177	200	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

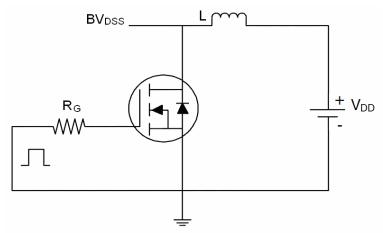
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=1mH,Rg=25 Ω

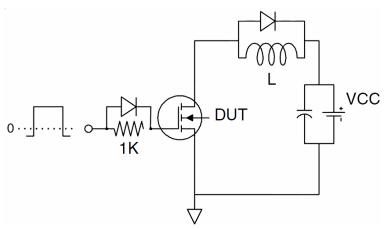


Test Circuit

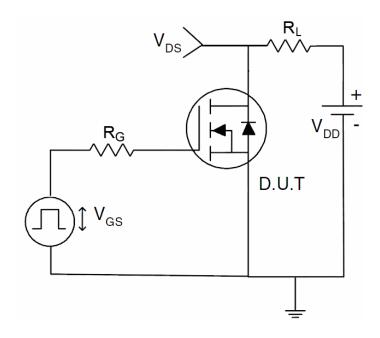
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

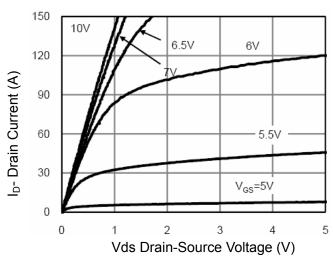


Figure 1 Output Characteristics

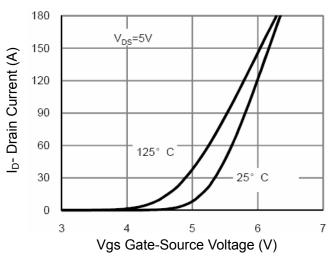


Figure 2 Transfer Characteristics

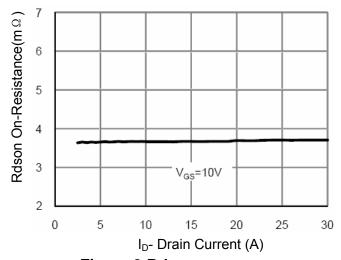


Figure 3 Rdson- Drain Current

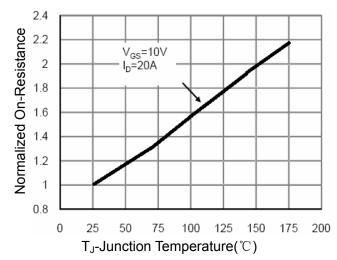


Figure 4 Rdson-JunctionTemperature

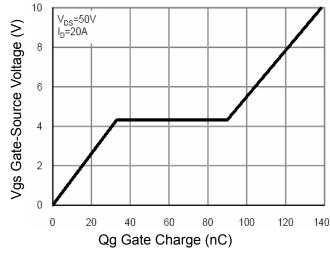


Figure 5 Gate Charge

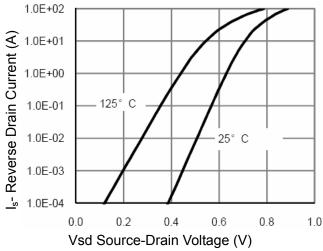
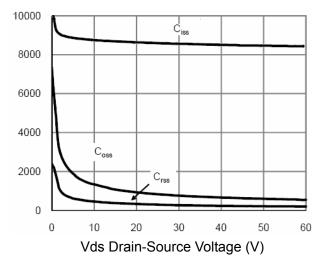


Figure 6 Source- Drain Diode Forward



C Capacitance (pF)



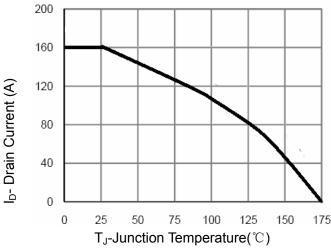
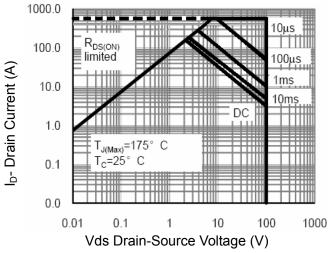


Figure 7 Capacitance vs Vds

Figure 9 ID Current- Junction Temperature





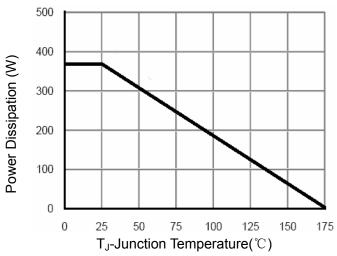


Figure 10 Power De-rating

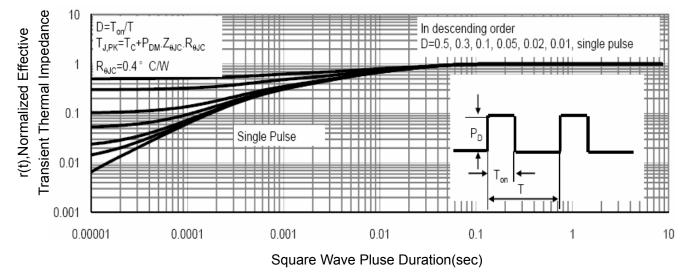


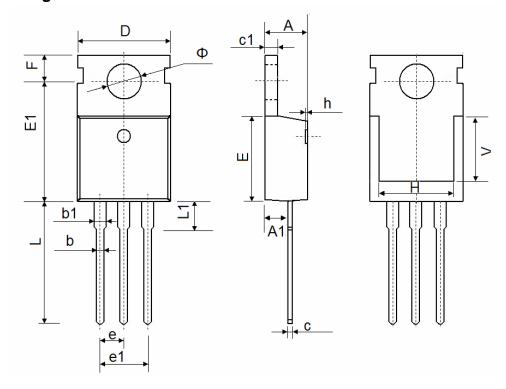
Figure 11 Normalized Maximum Transient Thermal Impedance

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Pb Free Product

NCE01H16

TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
Е	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.54	0 TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	

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